

## Ultralow Noise Microphone with Bottom Port and Analog Output

### DESCRIPTION

The ZTS6051E is a high quality, low cost, low power analog output bottom-ported omni-directional MEMS microphone. ZTS6051E consists of a MEMS microphone element and an preamplifier. ZTS6051E has a high SNR and flat wideband frequency response, resulting in natural sound with high intelligibility. Due to built-in filter, ZTS6051E shows high immunity to EMI.

The ZTS6051E is available in a thin 3.76mm × 2.95mm × 1.1mm surface-mount package. It is reflow solder compatible with no sensitivity degradation. The ZTS6051E is halide free.

### APPLICATIONS

- Mobile telephones
- PDAs
- Digital video cameras
- Portable media devices with audio input

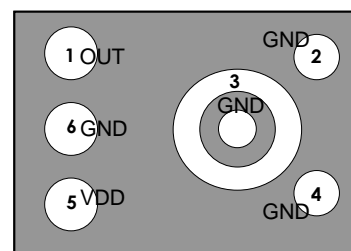
### ORDERING INFORMATION

PART	RoHS	Ship, Quantity
ZTS6051E	Yes	Tape and Reel, 5.2K

### FEATURES

- 3.76mm×2.95mm×1.1mm surface-mount package
- Stable sensitivity over power supply range of 1.5V-3.6V
- SNR of 63dBA
- Sensitivity of -38dBV
- Low current consumption of <math><100\mu\text{A}</math>
- Multi Chip Module (MCM) Package

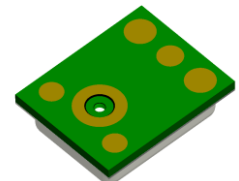
### Pins Configuration and Description



Bottom View



Top

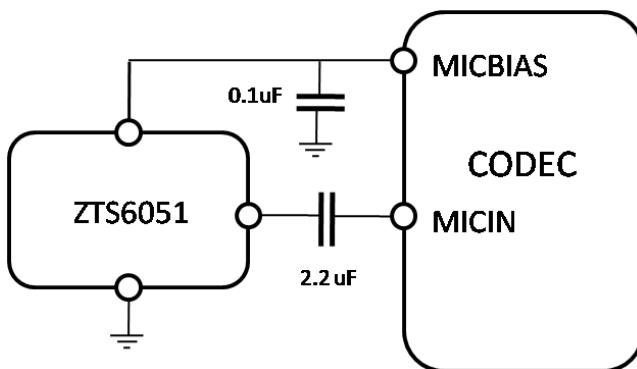


Bottom

Isometric Views of ZTS6051E Microphone Package

### Typical Applications

The ZTS6051E output can be connected to a codec microphone input or to a high input impedance gain stage. A dc-blocking capacitor is required at the output of the microphone.



Connect to Audio Codec

### Absolute Maximum Ratings

Supply Voltage ..... -0.5V to +4V  
 Sound Pressure Level ..... 160dB  
 Mechanical Shock ..... 10000g  
 Vibration ..... Per MIL-STD-883 Method  
 2007, Test Condition B  
 Temperature Range ..... -40°C to +70°C

**CAUTION:** Stresses above those listed in “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### Electro-Static Discharge Sensitivity

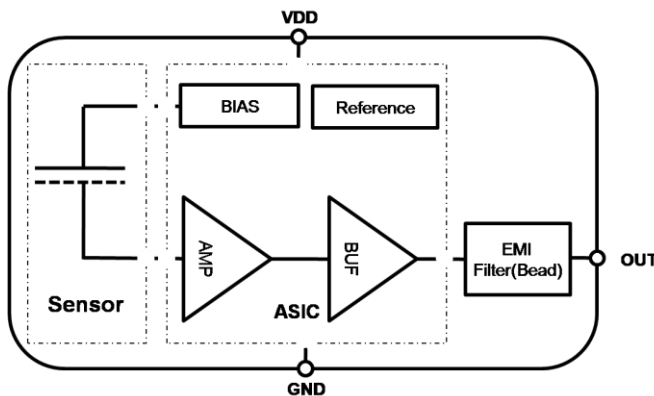


This integrated circuit can be damaged by ESD. It is recommended that all integrated circuits be handled with proper precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure.

### Pins Description

Pin	Symbol	Description
1	OUT	Analog output signal.
2,3,4,6	GND	Ground.
5	VDD	Power Supply.

### Functional Block Diagram



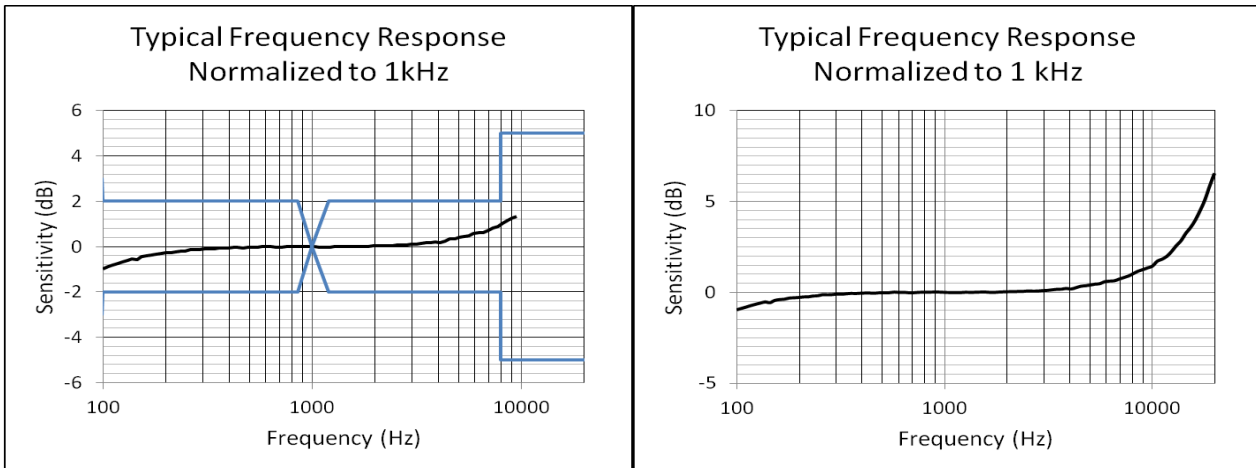
### Specifications

(T<sub>A</sub> = +15°C ~ +25°C, V<sub>DD</sub> = +1.8V, unless otherwise noted.)

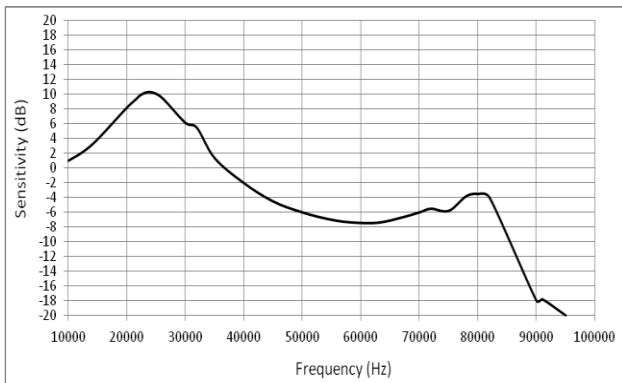
PARAMETER	Symbol	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Directivity				Omni		
Supply Voltage	V <sub>DD</sub>		1.5		3.6	V
Current Consumption	I <sub>DD</sub>			65	100	μA
Sensitivity (Note)		1kHz, 94dB SPL (TOLERANCE: +/- 1)	-39	-38	-37	dBV
Signal-to-Noise-Ratio	SNR			63		dB
Equivalent Input Noise	EIN			31		dBA SPL
Total Harmonic Distortion	THD	105dB SPL			3	%
Power Supply Rejection Ratio	PSRR	217Hz, 100mV Vp-p, square wave on V <sub>DD</sub>		65		dB
Maximum Acoustic Input				125		dB SPL
Output Impedance	Zout			300		Ω
Output DC Offset				0.7		V
Output Current Limit				90		μA
Polarity				Noninverting		

Note: Base on BK sound test system.

Typical Performance Characteristics



Frequency Response Normalized to 1kHz.



Preliminary Ultrasonic Free Field Response Normalized to 1KHz.

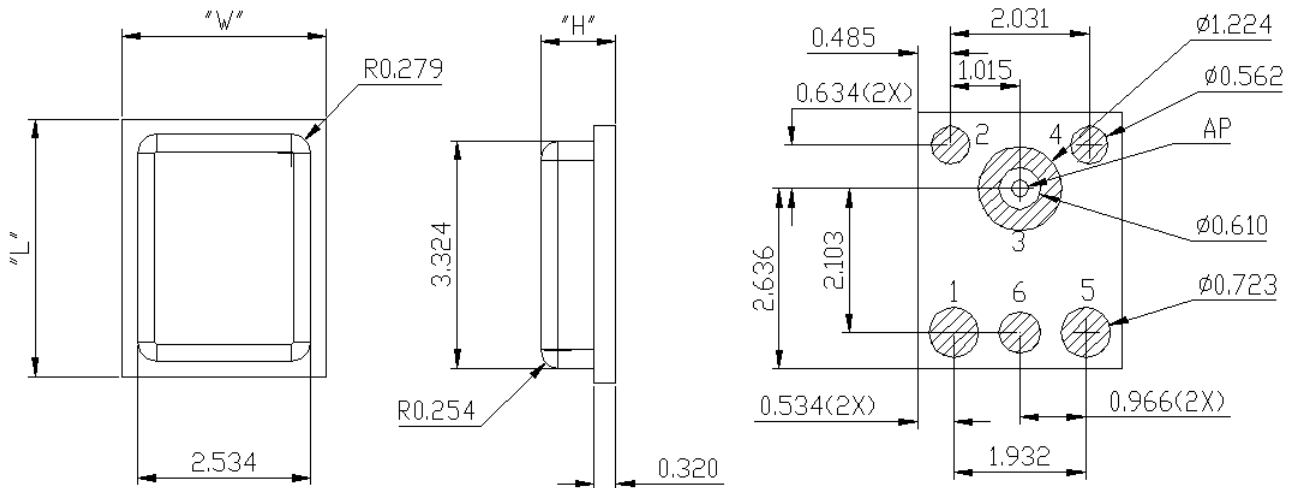
## Reliability Tests

The microphone sensitivity after stress must deviate by no more than  $\pm 3\text{dB}$  from the initial value.

1.Heat Test, Operational	Temperature: $85\pm 3^{\circ}\text{C}$ Humidity: $85\pm 5\%\text{RH}$ Duration: 12 hours Voltage: Applied
2.Cold Test, Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ Duration: 12 hours Voltage: Applied
3.Heat Test, Non-Operational	Temperature: $85\pm 3^{\circ}\text{C}$ Humidity: $50\pm 5\%\text{RH}$ Duration: 96 hours Voltage: Not Applied
4.Cold Test, Non-Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ Duration: 96 hours Voltage: Not Applied
5.Condensation Test, Non-Operational	Temperature: $25\pm 3^{\circ}\text{C}$ and $55\pm 3^{\circ}\text{C}$ Humidity: $95\pm 5\%\text{RH}$ Duration: 1 hours each, during 10 minutes ramp, 45 cycles Voltage: Not applied
6.Temperature Cycling, Non-Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ and $85\pm 3^{\circ}\text{C}$ Humidity: $50\pm 5\%\text{RH}$ Duration: 2 hours each, during 6 hours ramp, 5 cycles Voltage: Not applied
7.Thermal Shock Test, Non-Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ and $85\pm 3^{\circ}\text{C}$ Duration: 30 minutes each, during 5 minutes ramp, 256 cycles Voltage: Not applied
8.Free Fall Test 1.5m	Placed inside test fixture and dropped on concrete from height 1.5m. (1)3 times by 6 surfaces (2)1 times by 12 edges (3)1 times by 8 corners
9.Random Vibration	Temperature: $23\pm 5^{\circ}\text{C}$ Humidity: $35\sim 70\%\text{RH}$ Duration: 2 hours each axis(X,Y,Z) Power Spectral Density: 5Hz $0.10\text{m}^2/\text{s}^3(=1.0391*10^{-3}\text{g}^2/\text{Hz})$ 12Hz $2.20\text{m}^2/\text{s}^3(=22.8602*10^{-3}\text{g}^2/\text{Hz})$ 20Hz $2.20\text{m}^2/\text{s}^3(=22.8602*10^{-3}\text{g}^2/\text{Hz})$ 200Hz $0.04\text{m}^2/\text{s}^3(=0.41534*10^{-3}\text{g}^2/\text{Hz})$ 200Hz $0.04\text{m}^2/\text{s}^3(=0.41564*10^{-3}\text{g}^2/\text{Hz})$
10.Repeated Low Level Free Fall Test	Placed inside test fixture and dropped on rubber mat from height of 10cm. Each face 2500 times(Total 6 faces, 15000times)
11.1m Repeated Rotating Free Fall	Placed inside test fixture and dropped on steel sheet from height of 1.0m. 100 times(all faces) Rotation speed of barrel: 10~12 falls/minute
12.Free Fall Test for master box	Corner drop: Each Corner 1 time Edge drop: Each Edge 1 time Face drop: Each Face 1 time

13. Random Vibration for master box	Sinusoidal wave vibration Frequency: 5~50Hz Acceleration: 7.4m/s <sup>2</sup> (0.76G) Sweep speed: 9Hz/min(5~50Hz, one way 5 min) Test duration: Direction of Face 1-3 20min Direction of Face 2-4 20min Direction of Face 5-6 20min Sample and direction of vibration : 1 direction for 1 sample Package on vibrating table: Free
14. Substrate bending Test	Deflection: 3mm Rate: 0.5mm/sec
15. Adhesion	Load: 10 N Duration: 10 seconds
16. Electrostatic Discharge Test	Capacitance: 150pF Resistance: 330Ω Duration: 10 times Air Discharge: Level 3(+/-8kV) Direct contact discharge: Level 1 (+/-2kV)
17. ESD-Human Body Model	3 discharges of ±2 kV direct contact to I/O pins. (100pF, 1500Ω)
18. ESD-Charged Device Model	3 discharges of ± 500V direct contact to I/O pins.
19. ESD-Machine Mode	3 discharges of ±200 V direct contact to I/O pins.
20. Self alignment effect	Displacement: 0.15mm

**MECHANICAL SPECIFICATION**

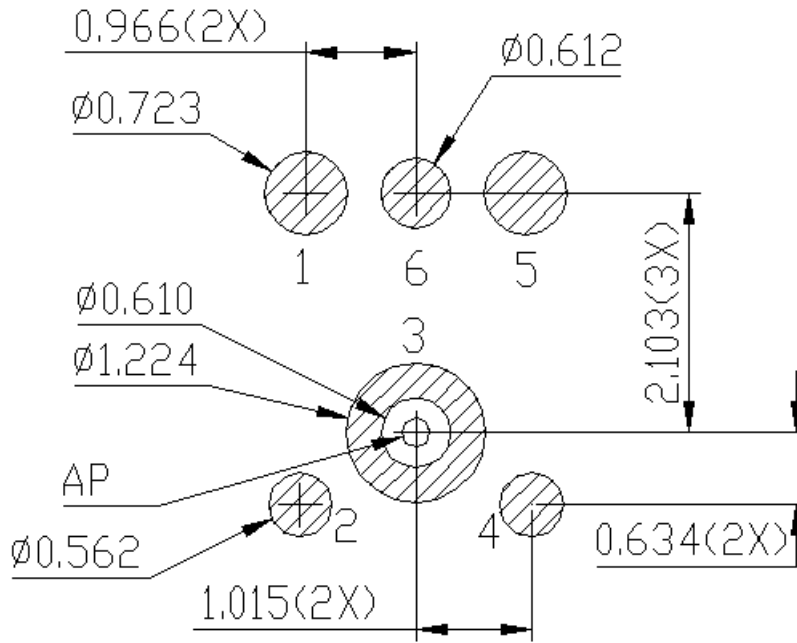


ITEM	DIMENSION	TOLERANCE	UNITS
Length (L)	3.760	±0.100	mm
Width (W)	2.950	±0.100	mm
Height (H)	1.100	±0.100	mm
<b>Acoustic Port (AP)</b>	$\phi 0.25$	±0.08	mm

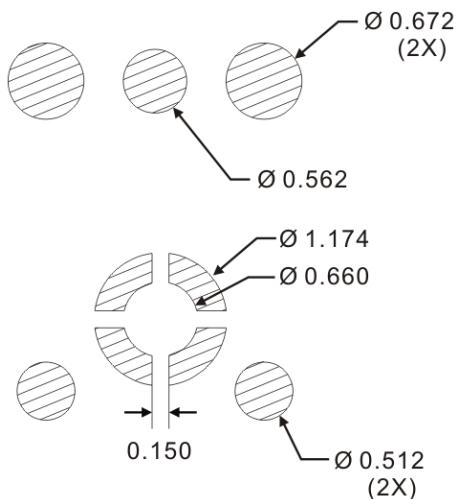
Pin#	Pin Name	Type	Description
1	OUTPUT	Signal	Output Signal
2	GND	Power	Ground
3	GND	Power	Ground
4	GND	Power	Ground
5	VDD	Power	Power Supply
6	GND	Power	Ground

## RECOMMENDED CUSTOMER LAND PATTERN

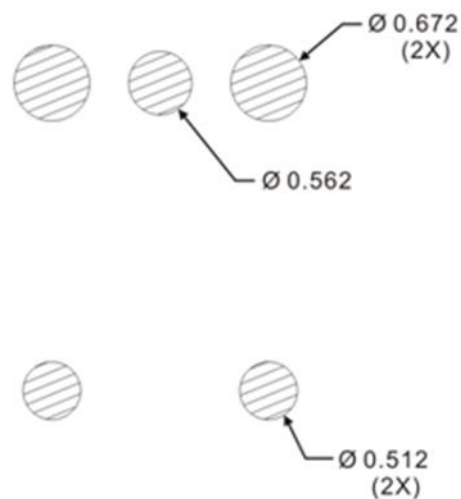
The recommended PCB land pattern for the ZTS6051E should have a 1:1 ratio to the solder pads on the microphone package. Care should be taken to avoid applying solder paste to the sound hole in PCB. The dimensions of suggested solder paste pattern refer to the land pattern. The thickness of solder is 0.1mm.



PCB Land Pattern Layout (Dimensions Shown in mm)



Solder Paste Stencil Pattern Layout with sealing.



Solder Paste Stencil Pattern Layout without Sealing.

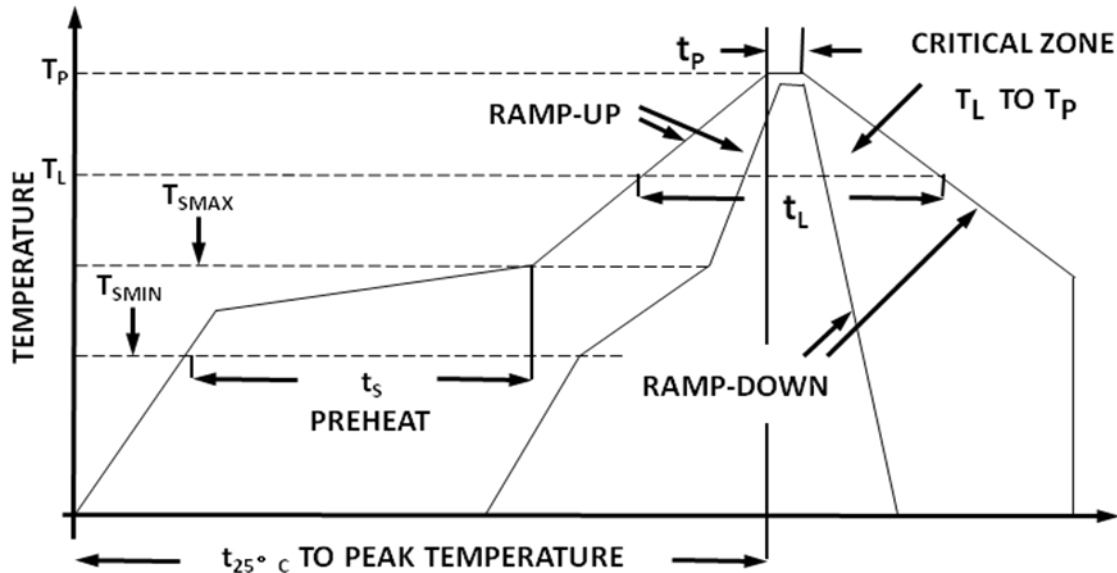
Note: Acoustic Port (AP) can be equal or smaller to inner ring of sealing PCB. Typically AP diameter can be adopted to be equal with inner ring size 0.61mm. If some special application is adopted, please check bottom port microphone

application design guide.

## SOLDER FLOW PROFILE

The reflow profile specified in this section describes expected maximum heat exposure of components during the reflow process of NMP product PWBs. Temperature is measured on top of component.

All components have to tolerate at least this profile five times (5x) without affecting electrical performance, mechanical performance or reliability.

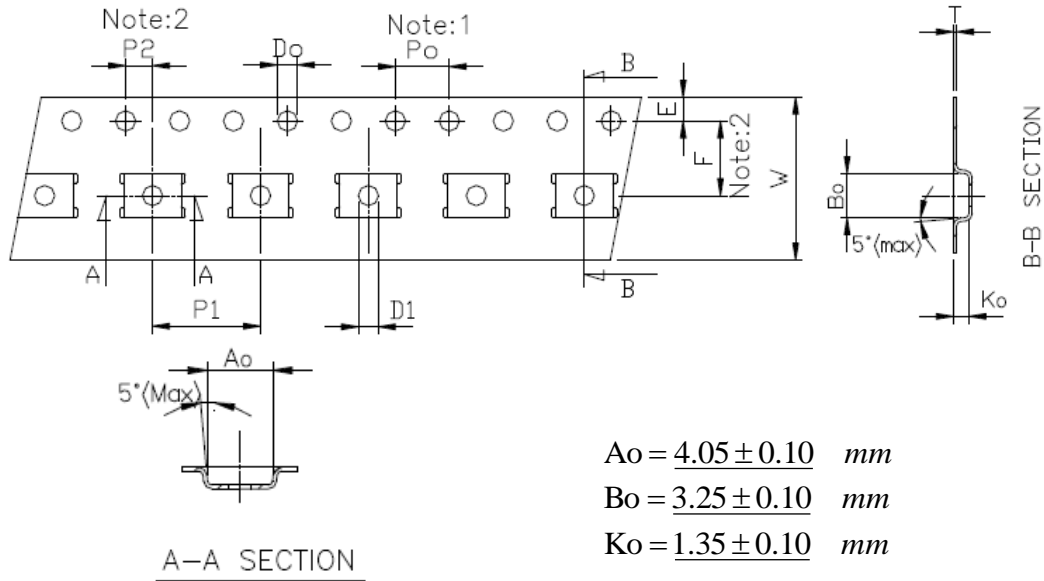


Pb-free and Sn63/Pb37 reflow profile requirements for soldering heat resistance:

Parameter	Reference	Pb-Free	Sn63/Pb37
Average Ramp Rate	$T_L$ to $T_P$	1.25°C/sec max	1.25°C/sec max
Preheat	Minimum Temperature	$T_{SMIN}$	100°C
	Maximum Temperature	$T_{SMAX}$	200°C
	Time	$T_{SMIN}$ to $T_{SMAX}$	60sec to 75sec
Ramp-Up Rate	$T_{SMAX}$ to $T_L$	1.25°C/sec	1.25°C/sec
Time Maintained Above Liquidous	$t_L$	50sec	60sec to 75sec
Liquidous Temperature	$T_L$	217°C	183°C
Peak Temperature	$T_P$	260°C +0°C/-5°C	215°C +3°C/-3°C
Time Within +5°C of Actual Peak Temperature	$t_p$	20 sec to 30 sec	20 sec to 30 sec
Ramp-Down Rate	$T_{peak}$	3°C/sec max	3°C/sec max
Time +25°C ( $t_{250c}$ ) to Peak Temperature		5 min max	5 min max



**PACKAGING**

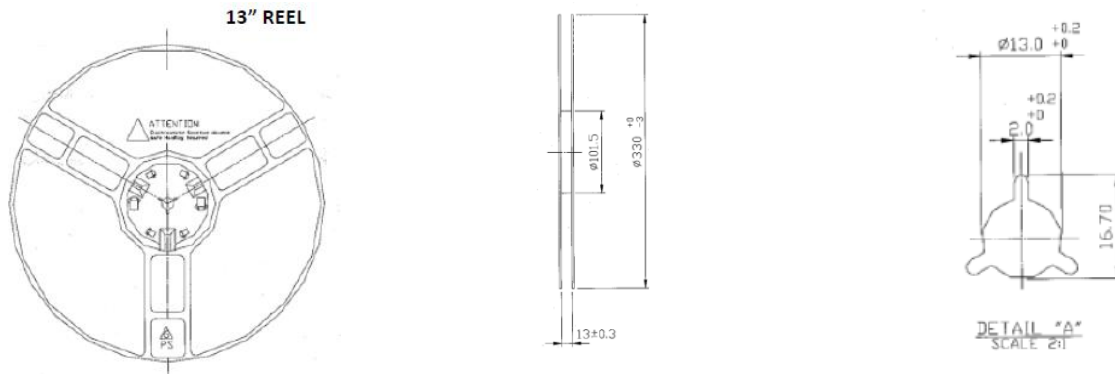


Unit : mm

Symbol	Spec.
K1	-
P <sub>o</sub>	4.0 ± 0.10
P1	8.0 ± 0.10
P2	2.0 ± 0.05
D <sub>o</sub>	1.55 ± 0.05
D1	1.50 (MIN)
E	1.75 ± 0.10
F	5.50 ± 0.05
10P <sub>o</sub>	40.0 ± 0.10
W	12.0 ± 0.20
T	0.30 ± 0.05

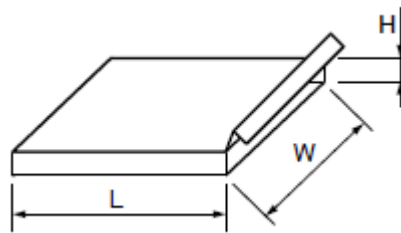
**Notice :**

- 10 Sprocket hole pitch cumulative tolerance is ± 0.1mm.
- Pocket position relative to sprocket hole measured as true position of pocket not pocket hole.
- A<sub>o</sub> & B<sub>o</sub> measured on a place 0.3mm above the bottom of the pocket to top surface of the carrier.
- K<sub>o</sub> measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- Carrier camber shall be not that 1mm per 100mm through a length of 250mm.



Part NO.	Reel Diameter	Quantity Per Reel	Quantity Per Inner Box	Quantity Per Outer Box
ZTS6051E	13"	5,200	5,200	46,800

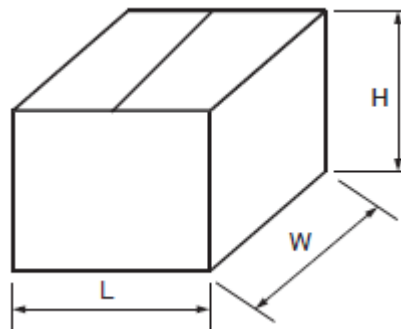
**Dimensions for Inner Box**



Unit : mm

L	W	H
335	339	45

**Dimensions for Outer Box**



Unit : mm

L	W	H
445	360	372